

HD74AC366

Hex Inverter Buffer with 3-State Output

REJ03D0270-0200Z (Previous ADE-205-391 (Z)) Rev.2.00 Jul.16.2004

Features

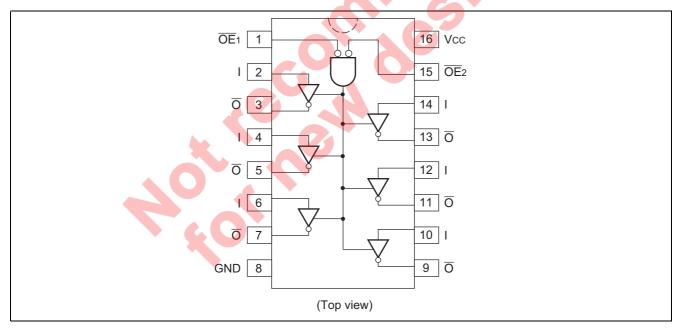
- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)
HD74AC366FPEL	SOP-16 pin (JEITA)	FP-16DAV	FP	EL (2,000 pcs/reel)
HD74AC366RPEL	SOP-16 pin (JEDEC)	FP-16DNV	RP	EL (2,500 pcs/reel)

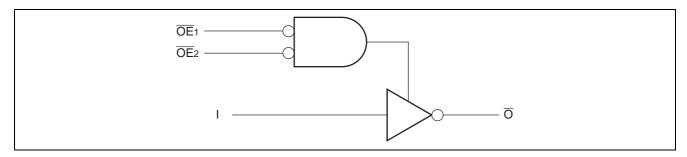
Notes: 1. Please consult the sales office for the above package availability.

2. The packages with lead-free pins are distinguished from the conventional products by adding V at the end of the package code.

Pin Arrangement



Logic Symbol



Pin Names

 \overline{OE}_1 , \overline{OE}_2 3-State Output: Enable Input (Active Low)

I Inputs O Outputs

Truth Table

Inputs			Output
ŌE₁	ŌĒ₂	1	0
L	L	L	Н
L	L	Н	L
X	Н	X	Z
Н	x	X	Z

H: High Voltage LevelL: Low Voltage LevelX: ImmaterialZ: High Impedance

Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	-0.5 to 7	V	
DC input diode current	I _{IK}	-20	mA	$V_1 = -0.5V$
		20	mA	$V_1 = Vcc+0.5V$
DC input voltage	V _I	-0.5 to Vcc+0.5	V	
DC output diode current	I _{ok}	-50	mA	$V_0 = -0.5V$
		50	mA	$V_O = Vcc+0.5V$
DC output voltage	Vo	-0.5 to Vcc+0.5	V	
DC output source or sink current	Io	±50	mA	
DC V _{cc} or ground current per output pin	I_{CC}, I_{GND}	±50	mA	
Storage temperature	Tstg	-65 to +150	°C	

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	Condition
Supply voltage	V _{cc}	2 to 6	V	
Input and Output voltage	V_{I}, V_{O}	0 to V _{CC}	V	
Operating temperature	Та	-40 to +85	°C	
Input rise and fall time	tr, tf	8	ns/V	$V_{CC} = 3.0V$
(except Schmitt inputs)				$V_{CC} = 4.5 \text{ V}$
V_{IN} 30% to 70% V_{CC}				V _{CC} = 5.5 V

DC Characteristics

Item	Sym- bol	Vcc (V)	٦	Га = 25°(C	Ta = -40 to +85°C		Unit	Condition	
			min.	typ.	max.	min.	max.			
Input Voltage	V _{IH}	3.0	2.1	1.5	_	2.1	—	V	$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$	
		4.5	3.15	2.25	_	3.15	_			
		5.5	3.85	2.75	—	3.85	—			
	V _{IL}	3.0	—	1.50	0.9	—	0.9		$V_{OUT} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$	
		4.5	—	2.25	1.35	—	1.35			
		5.5	_	2.75	1.65	_	1.65			
Output voltage	V_{OH}	3.0	2.9	2.99	—	2.9	—	V	$V_{IN} = V_{IL}$ or V_{IH}	
		4.5	4.4	4.49	_	4.4			$I_{OUT} = -50 \mu A$	
		5.5	5.4	5.49	_	5.4	_			
		3.0	2.58	_	_	2.48	_		$V_{IN} = V_{IL} \text{ or } V_{IH}$ $I_{OH} = -12 \text{ mA}$	
		4.5	3.94		_	3.80			$I_{OH} = -24 \text{ mA}$	
		5.5	4.94		_	4.80			$I_{OH} = -24 \text{ mA}$	
	V _{OL}	3.0	_	0.002	0.1	_	0.1		$V_{IN} = V_{IL}$ or V_{IH}	
		4.5	_	0.001	0.1	_	0.1		I _{OUT} = 50 μA	
		5.5	_	0.001	0.1	_	0.1			
		3.0	_	_	0.32	_	0.37		$V_{IN} = V_{IL}$ or V_{IH} $I_{OL} = 12 \text{ mA}$	
		4.5	_		0.32	- 4	0.37		$I_{OL} = 24 \text{ mA}$	
		5.5	_	_	0.32	-	0.37		$I_{OL} = 24 \text{ mA}$	
Input leakage current	I _{IN}	5.5	_	_	±0.1		±1.0	μΑ	$V_{IN} = V_{CC}$ or GND	
3 State current	I _{oz}	5.5	_	_	±0.5	_	±5.0	μΑ	$V_{IN(OE)} = V_{IL}, V_{IH}$	
									$V_{IN} = V_{CC}$ or GND	
									$V_{OUT} = V_{CC}$ or GND	
Dynamic output	I _{OLD}	5.5	_		_	86	/	mA	V _{OLD} = 1.1 V	
current*	I _{OHD}	5.5	-		-	–75	_	mA	V _{OHD} = 3.85 V	
Quiescent supply current	I _{cc}	5.5	1	-	8.0	-	80	μΑ	$V_{IN} = V_{CC}$ or ground	

^{*}Maximum test duration 2.0 ms, one output loaded at a time.

AC Characteristics

			Ta = +25°C		Ta = -40° C to $+85^{\circ}$ C C ₁ = 50 pF			
			($C_L = 50 p$	F	C _L = :	50 pF	
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Propagation delay	t _{PLH}	3.3	1.0	7.0	9.0	1.0	10.0	ns
		5.0	1.0	5.0	7.0	1.0	7.5	
Propagation delay	t _{PHL}	3.3	1.0	7.0	9.0	1.0	10.0	ns
		5.0	1.0	4.5	7.0	1.0	7.5	
Enable time	t _{zH}	3.3	1.0	9.0	13.0	1.0	13.5	ns
		5.0	1.0	7.0	9.5	1.0	10.0	
Enable time	t_{ZL}	3.3	1.0	10.0	12.5	1.0	13.5	ns
		5.0	1.0	7.5	9.5	1.0	10.0	
Disable time	t _{HZ}	3.3	1.0	9.5	12.0	1.0	12.5	ns
		5.0	1.0	7.5	10.0	1.0	10.5	
Disable time	t _{LZ}	3.3	1.0	9.0	12.5	1.0	13.5	ns
		5.0	1.0	7.0	10.0	1.0	10.5	

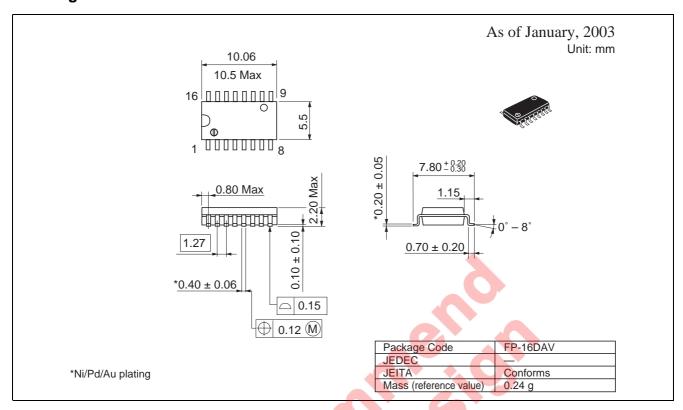
Note: 1. Voltage Range 3.3 is 3.3 V \pm 0.3 V Voltage Range 5.0 is 5.0 V \pm 0.5 V

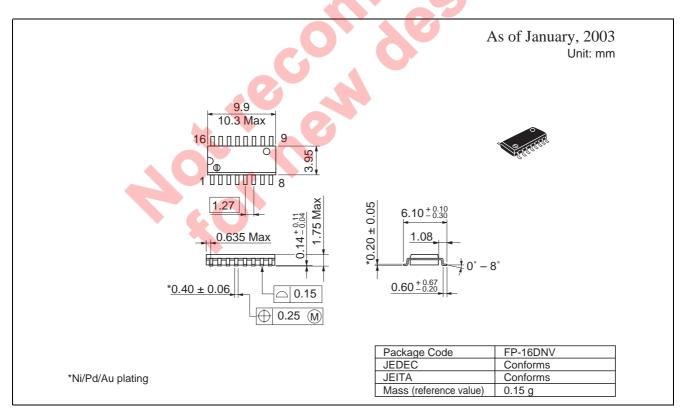
Capacitance

Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Power dissipation capacitance	C _{PD}	40.0	pF	V _{CC} = 5.0 V



Package Dimensions





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Renesas Technology Europe GmbH Dornacher Str. 3, D-85622 Feldkirchen, Germany Tel: <49> (89) 380 70 0, Fax: <49> (89) 929 30 11

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Renesas Technology (Shanghai) Co., Ltd. 26/F., Ruijin Building, No.205 Maoming Road (S), Shanghai 200020, China Tel: <86> (21) 6472-1001, Fax: <86> (21) 6415-2952

Renesas Technology Singapore Pte. Ltd.
1, Harbour Front Avenue, #06-10, Keppel Bay Tower, Singapore 098632 Tel: <65> 6213-0200, Fax: <65> 6278-8001

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